File: f:/coursesS11/303/303S11MdtrmMakup.doc RWN 03/30/11==>04/06/11 ENEE 303 Midterm MakupExam, Spring 2011

Your signature guarantees that you have not discussed this Exam after receiving this sheet. 56 points, open book, open notes.

Due Wednesday, April 6, 2011, Monday, April 11, at start of class.

Unless otherwise stated, for MOS transistors use 4007s, for BJTs assume Beta = 150 and for tail currents use 5mA. The 4007 Spice model parameters to be used are:

```
.model M4007N nmos(Level=1 Tox=300n Kp=20.54u W=144u L=8u Vto= 1.3
+ Lambda=15m Cbd=4p Cbs=4p)
.model M4007P pmos(Level=1 Tox=300n Kp=10.32u W=328u L=8u Vto=-1.5
+ Lambda=15m Cbd=8p Cbs=8p)
```

1. (10 points)



Using the above symbol for an OTA give the small signal Gm when biased at Vi=0 for (give in terms of literals and numerically)

a) a BJT OTA b) an MOS OTA

2. (10 points) Ideally an OTA can be modeled by the following curve [along with zero input current]



Give Gm in terms of the parameters indicated on the curve (not numerically)

3. (18 points)

The ideal OTA of problem 2 is connected as shown below in two different configurations (NOTE that the OTA inputs are reversed). Assuming they are to be used for small signals around zero, for each circuit:

- a. Set up the differential equation for the OTA input voltage (Va for (a) and Vb for (b))
- b. Give their impulse responses with Vin as input and Va and Vb as outputs in time.
- c. Discuss the reason and meaning of the differences between Va and Vb.



4. (18 points) For this circuit using a 4007 transistor



- a. Find the Q point values of VGS, ID and VDS; (be sure to include the Early effect and check the state of the transistor (saturation or Ohmic [=triode]).
- b. Give the gm, go, and small signal mid-band gain, vo/vin